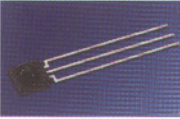



1. Foto IC für Fernsteuerung

T_A = 25 °C

1. Photo IC for Remote Control

T_A = 25 °C

Gehäuse Package	Typ Type	Frequenz Frequency f kHz	Halbwinkel Halfangle φ deg.	Min. Bestrahlungsstärke ¹⁾ Min. threshold irradiance E _{e min} mW/m ²	Ordering code	Fig.
	SFH 5110-30	30	± 50 horizontal ± 30 vertical	0.35 typ., 0.5 max.	Q62702-P5088	1
	SFH 5110-33	33				
	SFH 5110-36	36				
	SFH 5110-38	38				
	SFH 5110-40	40				
	SFH 5111-30	30	± 50 horizontal ± 30 vertical	0.35 typ., 0.5 max.	Q62702-P5257	
	SFH 5111-33	33				
	SFH 5111-36	36				
	SFH 5111-38	38				
	SFH 5111-40	40				
	SFH 5410	30	± 60 horizontal ± 60 vertical	1.4 typ., 2.0 max.	on request	
	SFH 5410	33			on request	
	SFH 5410	36			Q65110A 354	
	SFH 5410	38			on request	
	SFH 5410	40			Q65110A 151	

¹⁾ In Verbindung mit einer SFH 4510/4515 bei Betrieb mit I_F = 500 mA wird eine Reichweite von ca. 30 m erreicht.
Together with an IRED SFH 4510/4515 under operating conditions I_F = 500 mA an arrival distance of 30 m is possible.

2. Fotodetektoren in SMT
(Oberflächenmontage)

T_A = 25 °C




2. Photodetectors in SMT
(Surface Mount Technology)

T_A = 25 °C

Package	Type	φ deg.	Radiant sensitive area mm ²	I _{PCE} (λ = 950 nm, E _e = 0.1 mW/cm ² , V _{CE} = 5 V) μA	V _{CEO} V	λ _{10%} nm	t _r , t _f (I _C = 1 mA, V _{CC} = 5 V, R _L = 1 kΩ) μs	Ordering code	Fig.
---------	------	-----------	---	--	-----------------------	------------------------	--	---------------	------

2.1 SMT-Transistoren






2.1 SMT-Transistors

	SFH 3010	± 80	0.02	>25 (E _e = 0.5 mW/cm ²)	15 30 (t < 2 mn)	420 ... 1100	7	Q62702-P5555	69	
	SFH 320	± 60	0.045	≥16	35		–	7	Q62702-P961	2
	SFH 320-3			25 ... 50			7/8	Q62702-P390		
	SFH 320-3/4			25 ... 80			8	Q62702-P3602		
	SFH 320-4			40 ... 80			8	Q62702-P1606		
	SFH 3219	± 25		≥ 63		430...1150	7	Q62702-P5551	67	

Package	Type	ϕ deg.	Radiant sensitive area mm ²	I_{PCE} ($\lambda = 950$ nm, $E_0 = 0.1$ mW/cm ² , $V_{CE} = 5$ V) μ A	V_{CEO} V	$\lambda_{10\%}$ nm	t_r, t_f ($I_C = 1$ mA, $V_{CC} = 5$ V, $R_L = 1$ k Ω) μ s	Ordering code	Fig.
---------	------	----------------	---	---	----------------	------------------------	---	---------------	------





2.1 SMT-Transistoren

2.1 SMT-Transistors (cont'd)

	SFH 320 FA	± 60	0.045	≥ 16	35	740 ... 1100	–	Q62702-P988	2
	SFH 320 FA-3			25 ... 50			7	Q62702-P393	
	SFH 320 FA-3/4			25 ... 80			7/8	Q62702-P3601	
	SFH 320 FA-4			40 ... 80			8	Q62702-P1607	
	SFH 3211	± 60	0.045	≥ 16	35	420 ... 1100	–	Q62702-P5127	3
	SFH 3211-3			25 ... 50			8	on request	
	SFH 3211-3/4			25 ... 80			–	on request	
	SFH 3211-4			40 ... 80			–	on request	
	SFH 3211 FA	± 60	0.045	≥ 16	35	740 ... 1100	–	on request	3
	SFH 3211 FA-3			25 ... 50			7	on request	
	SFH 3211 FA-3/4			25 ... 80			7/8	on request	
	SFH 3211 FA-4			40 ... 80			8	on request	
	SFH 325	± 60	0.045	≥ 16	35	420 ... 1100	–	Q62702-P1638	4
	SFH 325-3			25 ... 50			7	Q62702-P1610	
	SFH 325-3/4			25 ... 80			7/8	Q62702-P3604	
	SFH 325-4			40 ... 80			8	Q62702-P1611	
	SFH 325 FA	± 60	0.045	≥ 16	35	740 ... 1100	–	Q62702-P1639	4
	SFH 325 FA-3			25 ... 50			7	Q62702-P1614	
	SFH 325 FA-3/4			25 ... 80			7/8	Q62702-P3603	
	SFH 325 FA-4			40 ... 80			8	Q62702-P1615	

SI-FOTODETEKTOREN








SILICON PHOTODETECTORS

Package	Type	Sender Emitter	λ_{peak} nm	ϕ deg.	I_V mcd	I_E mW/sr	V_F V		Ordering code	Fig.
 Multi TOPLED	SFH 331-JK	Sender Emitter	635	± 60	4...12.5	-	2.0	at $I_F = 20 \text{ mA}$	Q62702-P1634	5
		Empfänger Detector	Radiant sensitive area mm ²	$I_{PCE} (\lambda = 950 \text{ nm}, E_s = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V})$ μA	V_{CEO}	$\lambda_{10\%}$	$t_{r,t}$ ($I_C = 1 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$) μs			
		0.045	≥ 16	35	380... 1150	7				
 Multi TOPLED	SFH 7221	Sender Emitter	880	± 60	-	4	1.5	at $I_F = 20 \text{ mA}$	Q62702-P1819	6
		Empfänger Detector	Radiant sensitive area mm ²	$I_{PCE} (\lambda = 950 \text{ nm}, E_s = 0.1 \text{ mW/cm}^2, V_{CE} = 5 \text{ V})$ μA	V_{CEO}	$\lambda_{10\%}$	$t_{r,t}$ ($I_C = 1 \text{ mA}, V_{CC} = 5 \text{ V}, R_L = 1 \text{ k}\Omega$) μs			
		0.045	≥ 16	35	380... 1150	7				
 Multi TOPLED	SFH 7225	Sender Emitter	591	± 60	125 typ.		2.0	at $I_F = 20 \text{ mA}$	Q62702-P5319	5
		Empfänger Detector	Radiant sensitive area mm ²	$I_{PCE} (E_s = 1000 \text{ lx Standard light A}, V_{CE} = 5 \text{ V})$ μA	V_{CEO}	Crosstalk I_{PCE} ($I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$)				
		0.045	650 typ.	35	850 typ.					
 Multi TOPLED	SFH 7226	Sender Emitter	645	± 60	70 typ.		2.0	at $I_F = 20 \text{ mA}$	Q62702-P5320	5
		Empfänger Detector	Radiant sensitive area mm ²	$I_{PCE} (E_s = 1000 \text{ lx Standard light A}, V_{CE} = 5 \text{ V})$ μA	V_{CEO}	Crosstalk I_{PCE} ($I_F = 20 \text{ mA}, V_{CE} = 5 \text{ V}$)				
		0.045	650 typ.	35	850 typ.					

Package	Type	ϕ deg.	Radiant sensitive area mm ²	I_{PCE} ($\lambda = 950$ nm, $V_{CE} = 5$ V) mA	V_{CEO} V	$\lambda_{10\%}$ nm	$t_{r,t}$ ($I_C = 1$ mA, $V_{CC} = 5$ V, $R_L = 1$ k Ω) μ s	Ordering code	Fig.
---------	------	----------------	---	--	----------------	------------------------	--	---------------	------

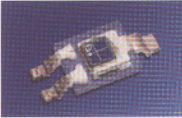
2.1 SMT-Transistoren

2.1 SMT-Transistors (cont'd)

	SFH 3500	± 13	0.55	2.5 ... 20.0	$E_o = 0.5$ mW/cm ²	35	450 ... 1060	–	Q62702-P5031	7
	SFH 3500-3/4			2.5 ... 8.0				14/17	Q62702-P5205	
	SFH 3500-5/6			6.3 ... 20.0				20/24	Q62702-P5206	
	SFH 3505	± 13	0.55	2.5 ... 20.0	$E_o = 0.5$ mW/cm ²	35	450 ... 1060	–	Q62702-P5050	8
	SFH 3505-3/4			2.5 ... 8.0				14/17	Q62702-P5207	
	SFH 3505-5/6			6.3 ... 20.0				20/24	Q62702-P5208	
	SFH 3500 FA	± 13	0.55	2.5 ... 20.0	$E_o = 0.5$ mW/cm ²	35	740 ... 1070	–	Q62702-P5032	7
	SFH 3500 FA-3/4			2.5 ... 8.0				14/17	Q62702-P5201	
	SFH 3500 FA-5/6			6.3 ... 20.0				20/24	Q62702-P5202	
	SFH 3505 FA	± 13	0.55	2.5 ... 20.0	$E_o = 0.5$ mW/cm ²	35	740 ... 1070	–	Q62702-P5051	8
	SFH 3505 FA-3/4			2.5 ... 8.0				14/17	Q62702-P5203	
	SFH 3505 FA-5/6			6.3 ... 20.0				20/24	Q62702-P5304	
	SFH 3400	± 60	0.55	0.063 ... 0.32	$E_o = 0.1$ mW/cm ²	20 70 ($t < 2$ min.)	460 ... 1080	–	Q62702-P1796	9
	SFH 3400-2/3			0.1 ... 0.32				24/34	Q62702-P3605	
	SFH 3401 (mit Basisanschluß/ with base connection)			0.063 ... 0.32				–	Q62702-P5014	
	SFH 3401-2/3	± 60	0.55	0.1 ... 0.32	$E_o = 0.1$ mW/cm ²	20 70 ($t < 2$ min.)	460 ... 1080	24/34	Q62702-P5200	10
	SFH 3201			0.063 ... 0.32				–	Q62702-P5043	
	SFH 3201-2/3	± 60	0.55	0.1 ... 0.32	$E_o = 0.1$ mW/cm ²	20 70 ($t < 2$ min.)	460 ... 1080	24/34	Q62702-P5209	11

SMT-Transistor (V_λ - Kurve)

SMT-Transistor (V_λ - Curve)

	SFH 3410	± 60	0.29	>0.0032	$E_v = 20$ Lx	5.5	350 ... 970	–	Q62702-P5160	12
	SFH 3410-1/2			0.0032-0.010				Q6511-0A49		
	SFH 3410-2/3			0.005 -0.016				Q6511-0A50		
	SFH 3410-3/4			0.008 -0.025				Q6511-0A51		